

Corrigendum

Corrigendum to “Thermal stress relaxation creep and microstructural evolutions of nanostructured SiC ceramics by liquid phase sintering” [J. Eur. Ceram. Soc. 30 (2010) 2643–2652]

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The authors regret that in the above-mentioned article the figure legends for Figs. 4 and 5 were incorrect. The correct legends are provided below.

Fig. 4 (a) STEM image and EDXS mappings of LPS-SiC at 1800 when hot-pressed and (b) elemental analysis on the selected points.

Fig. 5 STEM image and EDXS mappings at intergranular grain boundaries of LPS-SiC at 1900.

The authors would like to apologise for any inconvenience this may have caused to the readers of the journal.

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